

## **Information Disclosure Statement**

New U.S. Patent Application for  
METHOD FOR FABRICATING METAL-OXIDE  
SEMICONDUCTOR TRANSISTOR  
Our Ref. No.: P03H1035/US/cj

Reference No.:

(1) Dual-Workfunction Gate Engineering in a Corner Parasitic-  
Free Shallow-Trench-Isolation Complementary-Metal-Oxide-  
Semiconductor Technology

*(Japanese Journal of Applied Physics, Vol. 38, 1999 Publication Board, Pages 2232-2237)*

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LIST OF PATENTS AND PUBLICATIONS FOR APPLICANT'S INFORMATION DISCLOSURE STATEMENT

ATTY. DOCKET NO.: P68985US0      GROUP ART UNIT: Not Yet Assigned  
SERIAL NO.: New Application      FILING DATE: July 14, 2003  
APPLICANT(S): Sang-Don LEE      TODAY'S DATE: July 14, 2003

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U.S. PATENT DOCUMENTS

*EXAMINER INITIAL	DOCUMENT NUMBER	DATE	NAME	INT'L CLASS	SUB- CLASS	FILING DATE (If Appropriate)
	AA					
	AB					

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FOREIGN PATENT DOCUMENTS

	DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUB- CLASS	TRANSLATION (YES) (NO)
	AC					
	AD					
	AE					

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OTHER ART (Including Author, Title, Date, Pertinent Pages, Etc.)

AF Udo SCHWALKE, et al.; "Dual-Workfunction Gate Engineering in a Corner Parasitics-Free Shallow-Trench-Isolation Complementary-Metal-Oxide-Semiconductor Technology"; Jpn. J. Appl. Phys. Vol. 38; 1999; pp.2232-2237.

AG \_\_\_\_\_

EXAMINER \_\_\_\_\_ DATE CONSIDERED \_\_\_\_\_

\* EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant(s).

## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Patent Application of: Sang-Don LEE  
Serial No.: New Application      Group Art Unit: Not Yet Assigned  
Filed: July 14, 2003      Examiner: Not Yet Assigned  
Title: METHOD FOR FABRICATING METAL-OXIDE SEMICONDUCTOR TRANSISTOR

INFORMATION DISCLOSURE STATEMENT

Honorable Commissioner for Patents  
PO Box 1450,  
Alexandria, VA 22313

July 14, 2003

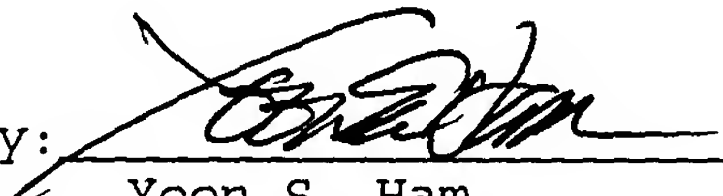
Sir:

As a means of complying with the duty of disclosure under 37 CFR §1.56, and in accordance with 37 CFR §§1.97 and 1.98, Applicant(s), through the undersigned attorney, submits this Information Disclosure Statement. The patents, publications or other information submitted herewith are listed on the attached Form PTO-1449 and copies are attached.

In accordance with 37 CFR §1.97(b)(1) or (2), this Information Disclosure Statement is being filed either within three months of the filing date of the above-identified application, or within three months of the date of entry into the national stage of the above-identified application as set forth in 37 CFR §1.491. Accordingly, no fee is required.

Respectfully submitted,

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